

## **Real time SEM imaging of FIB milling processes for extended accuracy in Cross Sectioning and TEM Preparation**

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In recent years focused ion beam (FIB) systems were routinely used for site specific cross sectioning and sample preparation for the transmission electron microscope (TEM). A wide range of different materials such as metals, semiconductors, ceramics and even biological substances can be covered. By combining the technique of focused ion beam and field emission scanning electron microscopy FESEM into an integrated CrossBeam<sup>®</sup> tool the accuracy of TEM sample preparation and cross sectioning has been significantly extended. In this article we report on improvements made in SEM cross sectioning and TEM sample preparation by using the newly developed CrossBeam<sup>®</sup> technology.

In a standard FIB cross sectioning the sample surface is imaged with the FIB before cutting to determine the area of interest. After this the sample is milled and polished with predefined milling patterns. Without the possibility of monitoring the milling process directly the area of interest is easily destroyed.

The capability of CrossBeam<sup>®</sup> tools to image the sample in real time at high resolution during the ion milling process gives the operator direct control to the ion milling process. This results in an interactive process that leads to an extended accuracy on site specific cross sections. The milling and polishing process can be stopped exactly at the detail of interest (FIG.1). Especially in the case of TEM sample preparation the danger of destroying the fine lamella is reduced to a minimum.

Another advantage of the CrossBeam<sup>®</sup> technology is the time saving cut and see operation. The sample is imaged during or immediately after the polishing. This leads to extremely short inspection times for each cross section.

Several TEM sample preparation techniques using FIB, such as pre-thinning and lift-out techniques (FIG. 2) have been published [1-3]. The FIB lift-out technique allows thin membranes to be extracted from bulk material, which saves a lot of sample pre-thinning time and is very successful in the preparation of site specific cross sections and planar samples.

Although TEM sample preparation can be automated by using scripts and macros the best accuracy is achieved if the milling is done manually with direct SEM observation. In a first step the sample is milled and polished from the front side under continuous SEM control until the detail of interest is visible. In the second step the sample is rotated by 180° and the backside of the sample is milled and polished under continuous SEM control until the desired thickness is achieved (FIG. 2). By imaging the TEM sample in the SEM the danger of destroying the TEM lamella due to drift etc. is minimised. Another opportunity of the direct SEM imaging is a the defined control of the specimen thickness and electron transparency during the ion milling process.

The best result concerning time and accuracy is achieved if different samples are pre-thinned automatically overnight to a thickness of about 1µm and then polished manually under high resolution SEM observation.

## References

- [1] P. Gnauck et. al., A new SEM / FIB CrossBeam<sup>®</sup> Inspection Tool for high Resolution Materials and Device Characterisation, Photonics West, San Jose, Ca, USA January 24– 31, 2003.
- [2] R. Rai, S. Subramanian, S. Rose, J. Conner, P. Schani, J. Moss, ISTFA 2000, p415
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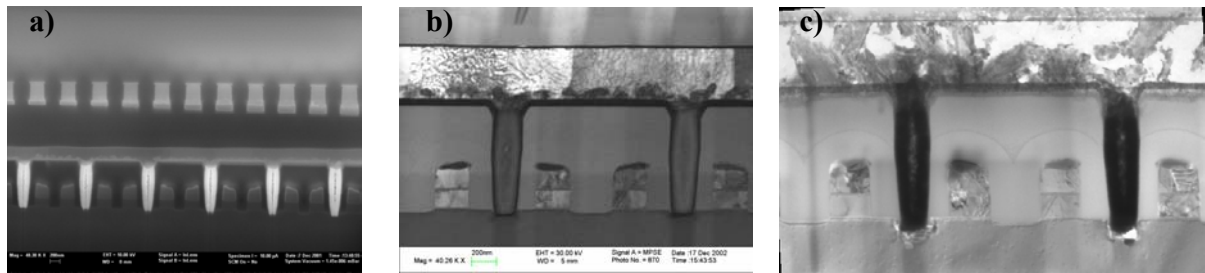


FIG. 1: a) Cross section through tungsten plugs in a semiconductor device. The milling process was stopped exactly in the centre of the plugs, b) 30keV STEM image, c) Bright field TEM image

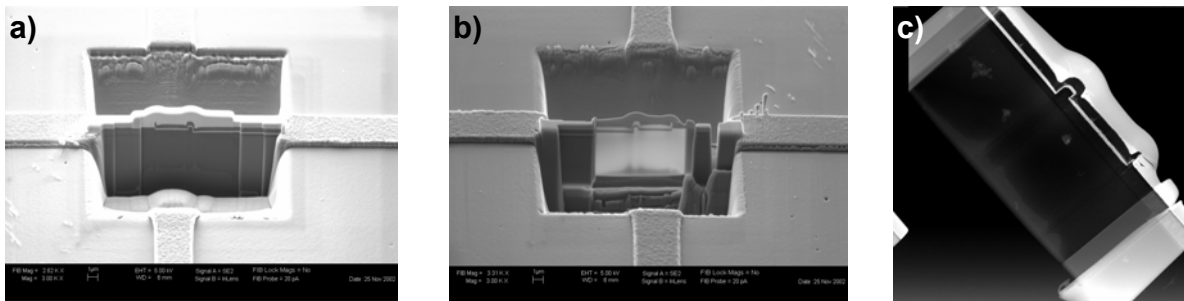


Fig. 2. Lift-out Procedure in CrossBeam<sup>®</sup> FIB Preparation: a) Rough mill b) Final mill, polish and cut out c) after lift-out of the TEM lamella.